Absolute Maximum Ratings

Parameter	Symbol	Value	Unit
Input Voltage (for V _O = 5V to 12V) (for V _O = 15V)	VI	35 40	V V
Power Dissipation	PD	Internally limited	-
Thermal Resistance, Junction to Air (Note1, 2) Ta = +25°C	RθJA	65	°C/W
Thermal Resistance, Junction to Case (Note1) Tc = +25°C	RθJC	2.5	°C/W
Operating Junction Temperature Range	TJ	0 ~ +125	°C
Storage Temperature Range	T _{STG}	-65 ~ +150	°C

Note:

- Thermal resistance test board Size: 76.2mm * 114.3mm * 1.6mm(1S0P) JEDEC standard: JESD51-3, JESD51-7
- 2. Assume no ambient airflow.

Electrical Characteristics(KA78T05)

(VI = 10V, IO = 3.0 A, 0° C \leq TJ \leq +125 $^{\circ}$ C, Po \leq PMAX (Note3), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5mA \le lo \le 3.0A$, $T_J = +25^{\circ}C$ $7.3V \le VI \le 20V$, $5mA \le lo \le 2.0A$		5.0 5.0	5.2 5.25	V
Line Regulation (Note4)	ΔVο	7.2V ≤ VI ≤ 35V, lo=5mA, TJ = +25°C 7.2V ≤ VI ≤ 35V, lo=1.0A, TJ = +25°C 7.5V ≤ VI ≤ 20V, lo =2.0A, TJ = +25°C 8.0V ≤ VI ≤ 12V, lo =3.0A, TJ = +25°C		3.0	25	mV
Load Regulation (Note4)	ΔVο	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{ TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C	-	0.002	0.03	%Vo/W
Quiescent Current	IQ	$5mA \le Io \le 3.0A, T_J = +25^{\circ}C$ $5mA \le Io \le 3.0A$	-	3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$7.2V \le VI \le 35V$, Io = 5mA $T_J = +25^{\circ}C$; $7.5V \le VI \le 20V$, Io =2.0A; $5mA \le Io \le 3.0A$, $T_J = +25^{\circ}C$	-	0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz, 8V \le V_I \le 18V, I_0 = 2.0A$ $T_J = +25$ °C	-	75	-	dB
Dropout Voltage	VD	lo = 3A ,TJ = +25°C	-	2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C$, $10Hz \le f \le 100kHz$	-	10	-	μV/Vo
Peak Output Current	IPK	TA = +25°C	-	5.0	•	Α
Output Resistance	Ro	f = 1.0kHz	-	2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 35V, TJ =+25°C	-	1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔV0/ΔΤ	Io = 5.0mA	-	0.2	ı	mV/°C

Note:

- 3. Although power dissipation is internally limited, specifications apply only for $P_0 \le P_0 \le$
- 4. Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used.

Electrical Characteristics(KA78T12) (Continued)

(VI = 19V, IO = 3.0 A, 0° C \leq TJ \leq +125 $^{\circ}$ C, Po \leq PMAX (Note1), unless otherwise specified.)

Parameter	Symbol	Conditions		Тур.	Max.	Unit
Output Voltage	Vo	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{ T}_{\text{J}} = +25^{\circ}\text{C}$ $14.5\text{V} \le \text{VI} \le 27\text{V}, 5\text{mA} \le \text{lo} \le 2.0\text{A}$		12 12	12.5 12.8	V
Line Regulation (Note2)	ΔVο	$14.5V \le VI \le 35V$, $Io=5mA$, $T_J = +25^{\circ}C$ $14.5V \le VI \le 35V$, $Io=1.0A$, $T_J = +25^{\circ}C$ $14.9V \le VI \le 28V$, $Io = 2.0A$, $T_J = +25^{\circ}C$ $16V \le VI \le 22V$, $Io = 3.0A$, $T_J = +25^{\circ}C$		6.0	45	mV
Load Regulation (Note2)	ΔVο	$5\text{mA} \leq \text{Io} \leq 3.0\text{A}, \text{ T}_\text{J} = +25^{\circ}\text{C}$ $5\text{mA} \leq \text{Io} \leq 3.0\text{A}$	-	10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C		0.002	0.03	%Vo/W
Quiescent Current	IQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$		3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$14.5V \le VI \le 35V$, $Io = 5mA$ $T_J = +25^{\circ}C$; $14.9V \le VI \le 27V$, $Io = 2.0A$ $5mA \le Io \le 3.0A$, $T_J = +25^{\circ}C$		0.1	0.8	mA
Ripple Rejection	RR	$f = 120$ Hz, 15 V \leq VI \leq 25V, $10 = 2.0$ A TJ =+25°C		67	-	dB
Dropout Voltage	VD	Io = 3A ,T _J =+25°C		2.2	2.5	V
Output Noise Voltage	VN	$T_A = +25^{\circ}C$, $10Hz \le f \le 100kHz$		10	-	μV/Vo
Peak Output Current	IPK	T _A =+25°C		5.0	-	Α
Output Resistance	Ro	f = 1.0kHz		2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 35V, TJ =+25°C		1.5	2.5	Α
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔΤ	Io = 5.0mA	-	0.5	-	mV/°C

Note:

- 1. Although power dissipation is internally limited, specifications apply only for Po ≤ Pmax, Pmax = 25W
- 2. Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. (PMAX = 25W)

Electrical Characteristics(KA78T15) (Continued)

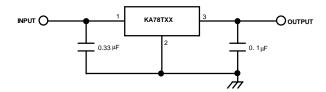
(VI = 23V, IO = 3.0A, 0° C \leq TJ \leq +125 $^{\circ}$ C, Po \leq PMAX (Note1), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Output Voltage	Vo	$5mA \le Io \le 3.0A$, $T_J = +25^{\circ}C$ $17.5V \le VI \le 30V$, $5mA \le Io \le 2.0A$		15 15	15.6 15.75	V
Line Regulation (Note2)	ΔVο	17.6V ≤ VI ≤ 40V, Io=5mA, TJ =+25°C 17.6V ≤ VI ≤ 40V, Io=1.0A, TJ =+25°C 18V ≤ VI ≤ 30V, Io =2.0A, TJ =+25°C 20V ≤ VI ≤ 26V, Io =3.0A, TJ =+25°C		7.5	55	mV
Load Regulation (Note2)	ΔVο	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{T}_{\text{J}} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$		10 15	30 80	mV mV
Thermal Regulation	REGT	Pulse =10ms, P = 20W TA = +25°C		0.002	0.03	%Vo/ W
Quiescent Current	lQ	$5\text{mA} \le \text{lo} \le 3.0\text{A}, \text{TJ} = +25^{\circ}\text{C}$ $5\text{mA} \le \text{lo} \le 3.0\text{A}$		3.5 4.0	5.0 6.0	mA mA
Quiescent Current Change	ΔlQ	$17.6V \le VI \le 40V$, $Io = 5mA$ $T_J = +25^{\circ}C$; $18V \le VI \le 30V$, $Io = 2.0A$; $5mA \le Io \le 3.0A$, $T_J = +25^{\circ}C$		0.1	0.8	mA
Ripple Rejection	RR	$f = 120Hz$, $18.5V \le V_I \le 28.5V$, $Io = 2.0A$ $T_J = +25^{\circ}C$		65	-	dB
Dropout Voltage	VD	lo = 3A,T _J =+25°C	-	2.2	2.5	V
Output Noise Voltage	VN	T _A =+25°C, 10Hz ≤ f ≤ 100kHz		10	-	μV/Vo
Peak Output Current	IPK	T _A =+25°C		5.0	-	Α
Output Resistance	Ro	f = 1.0kHz		2.0	-	mΩ
Short Circuit Current Limit	Isc	VI = 40V, TJ =+25°C	ı	1.0	2.0	Α
Average Temperature Coefficient of Output Voltage	ΔV _O /ΔT	Io = 5.0mA		0.5	-	mV/°C

Note:

- 1. Although power dissipation is internally limited, specifications apply only for Po ≤ Pmax, Pmax = 25W
- 2. Load and line regulation are specified at constant junction temperature. Change in Vo due heating effects must be taken into account separately. Pulse testing with low duty is used. (PMAX = 25W)

Typical Application



Notes:

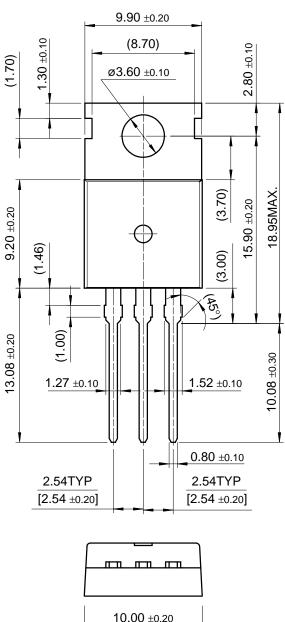
- 1. To specify an output voltage, substitute voltage value for "XX".
- 2. Bypass Capacitors are recommend for optimum stability and transient response and should be located as close as possible to the regulator

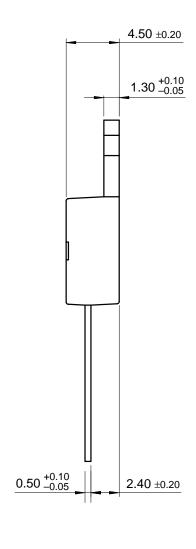
Mechanical Dimensions

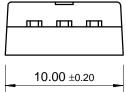
Package

Dimensions in millimeters

TO-220







Ordering Information

Product Number	Package	Operating Temperature
KA78T05		
KA78T12	TO-220	0 ~ +125°C
KA78T15		

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